## <u>The Common Source Amp</u> with Enhancement Load



**Q:** What is the small-signal open-circuit voltage gain, input resistance, and output resistance of this amplifier?

A: The values that we will determine when we follow precisely the same steps as before!!



Continuing with the **ANALYSIS**, we can find the drain current through the enhancement load  $(I_{D2})$ , since it is equal to the current through  $Q_1$ :

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$$\boldsymbol{I}_{D2} = \boldsymbol{I}_{D1} = \boldsymbol{K}_{1} \left( \boldsymbol{V}_{\mathcal{G}} - \boldsymbol{V}_{t1} \right)^{2}$$

Yet we also know that  $V_{GS2}$  must be related to this drain current as:

$$I_{D2} = K_2 \left( V_{GS2} - V_{t2} \right)^2$$

and therefore combining the above equations:

$$\boldsymbol{I}_{D1} = \boldsymbol{I}_{D2}$$
$$\boldsymbol{K}_{1} \left( \boldsymbol{V}_{G} - \boldsymbol{V}_{t1} \right)^{2} = \boldsymbol{K}_{2} \left( \boldsymbol{V}_{G52} - \boldsymbol{V}_{t2} \right)^{2}$$

Note this last equation has only one unknown  $(V_{G52})$ ! Rearranging, we find that:

$$V_{GS2} = \sqrt{\frac{K_1}{K_2}} \left( V_G - V_{t1} \right) + V_{t2}$$

Since  $V_{DS2} = V_{GS2}$  and  $V_{DS1} = V_{DD} - V_{DS2}$ , we can likewise state that:

$$V_{D52} = \sqrt{\frac{K_1}{K_2}} \left( V_G - V_{t1} \right) + V_{t2}$$

and:

$$V_{DS1} = V_{DD} - V_{t2} - \sqrt{\frac{K_1}{K_2}} \left( V_{\mathcal{G}} - V_{t1} \right)$$

Now, we must CHECK to see if our assumption is correct.

The saturation assumption will be correct if:

$$V_{D51} > V_{G51} - V_{t1}$$
$$> V_G - V_{t1}$$

and:

$$V_{GS1} > V_{t1}$$
  $\therefore$  if  $V_G > V_{t1}$ 

Step 2 - Calculate small-signal parameters

We require the small-signal parameters for each of the transistors  $Q_1$  and  $Q_2$ . Therefore:

$$g_{m1} = 2K_1(V_G - V_{t1})$$
 and  $g_{m2} = 2K_1(V_{GS2} - V_{t2})$ 

and:

$$r_{o1} = \frac{1}{\lambda_1 I_D}$$
 and  $r_{o2} = \frac{1}{\lambda_2 I_D}$ 



## First, let's turn off the DC sources:



We now replace **MOSFET**  $Q_1$  with its equivalent small-signal model, and replace the enhancement load with its equivalent small-signal model.



7/9 Simplifying further, we find:  $(g_{m1}v_{gs1} - g_{m2}v_{gs2}) + r_{o1} \|r_{o2} + r_{o1}\|$ V<sub>gs1</sub> Therefore, we find that:  $V_{qs1} = V_i$ and that:  $V_{gs2} = -V_o$ as well as that:  $v_{o} = -(g_{m1}v_{os1} - g_{m2}v_{os2})(r_{o1}||r_{o2})$  $= -(g_{m1}v_{i} + g_{m2}v_{a})(r_{a1} || r_{a2})$ Rearranging, we find:  $\mathcal{A}_{o} = \frac{V_{o}}{V} = \frac{-(r_{o1} \| r_{o2})g_{m1}}{1 + (r_{o1} \| r_{o2})g_{m2}} \approx \frac{-g_{m1}}{g_{m2}}$ But recall that:  $g_m = 2K(V_{GS} - V_t)$  $=2\sqrt{K}\sqrt{I_{D}}$ where we have used the fact that  $I_{D} = K (V_{GS} - V_{t})^{2}$  to

determine that  $(V_{GS} - V_{t}) = \sqrt{I_D/K}$ .



$$\mathcal{A}_{o} = \frac{-g_{m1}}{g_{m2}} = \frac{2\sqrt{K_{1}}\sqrt{I_{D}}}{2\sqrt{K_{2}}\sqrt{I_{D}}} = \sqrt{\frac{K_{1}}{K_{2}}} = \frac{\sqrt{\frac{W}{L}}}{\sqrt{\frac{W}{L}}}$$

In other words, we adjust the MOSFET channel geometry to set the small-signal gain of this amplifier!

Now let's determine the small-signal input and output resistances of this amplifier!



It is evident that since  $i_i = i_q = 0$ :

$$R_{i} = \frac{V_{i}}{i} = \infty \qquad \text{(Great!!!)}$$

Now for the output resistance, we know that the open-circuit output voltage is:

$$\boldsymbol{v}_{o}^{oc} = -(\boldsymbol{g}_{m1} \, \boldsymbol{v}_{gs1} - \boldsymbol{g}_{m2} \, \boldsymbol{v}_{gs2})(\boldsymbol{r}_{o1} \, \| \boldsymbol{r}_{o2})$$



Likewise, the short-circuit output current  $i_{o}^{sc}$  is:

$$\dot{F}_{os} = -(g_{m1}v_{gs1} - g_{m2}v_{gs2})$$

Thus, the small-signal output resistance of this amplifier is equal to:

$$R_{o} = \frac{v_{o}^{oc}}{i_{o}^{sc}} = \frac{-(g_{m1}v_{gs1} - g_{m2}v_{gs2})(r_{o1} || r_{o2})}{-(g_{m1}v_{gs1} - g_{m2}v_{gs2})} = (r_{o1} || r_{o2}) \quad \text{(Doh!!!)}$$

The input resistance and open-circuit voltage gain of this common source amplifier are good, but the output resistance stinks!!

Smells like a common emitter amplifier!

